# **Quad 2-Input OR Gate**

# High–Performance Silicon–Gate CMOS

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### Features

• Outputs Source/Sink 24 mA

13

12

V<sub>CC</sub>

14

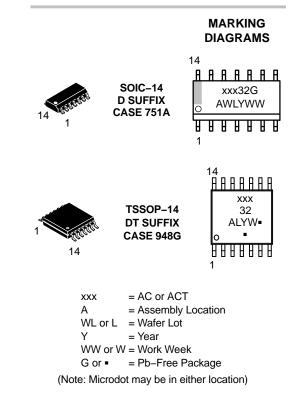
- 'ACT32 Has TTL Compatible Inputs
- These Devices are Pb-Free and are RoHS Compliant

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# 3 4 5 6 7 GND

Figure 1. Pinout: 14–Lead Packages Conductors (Top View)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

#### MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
VI	DC Input Voltage		$-0.5 \leq V_{I} \leq V_{CC} + 0.5$	V
Vo	DC Output Voltage	(Note 1)	$-0.5 \leq V_O \leq V_{CC} + 0.5$	V
I <sub>IK</sub>	DC Input Diode Current		±20	mA
I <sub>OK</sub>	DC Output Diode Current		±50	mA
IO	DC Output Sink/Source Current		±50	mA
I <sub>CC</sub>	DC Supply Current per Output Pin		±50	mA
I <sub>GND</sub>	DC Ground Current per Output Pin		±50	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
TL	Lead temperature, 1 mm from Case for 10 Secon	ds	260	°C
TJ	Junction temperature under Bias		+ 150	°C
$\theta_{JA}$	Thermal Resistance (Note 2)	SOIC TSSOP	125 170	°C/W
P <sub>D</sub>	Power Dissipation in Still Air at 85°C	SOIC TSSOP	125 170	mW
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating Oxy	/gen Index: 30% – 35%	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	Ň	an Body Model (Note 3) Machine Model (Note 4) I Device Model (Note 5)	> 2000 > 200 > 1000	V
I <sub>Latch-Up</sub>	Latch–Up Performance Above V <sub>CC</sub> and Below	v GND at 85°C (Note 6)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I<sub>O</sub> absolute maximum rating must be observed.

2. The package thermal impedance is calculated in accordance with JESD51-7.

3. Tested to EIA/JESD22-A114-A.

Tested to EIA/JESD22–A115–A.
 Tested to JESD22–C101–A.

6. Tested to EIA/JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter			Тур	Max	Unit
		′AC	2.0	5.0	6.0	
V <sub>CC</sub>	Supply Voltage	Ϋ́ACT	4.5	5.0	5.5	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Ref. to GND)		0	-	V <sub>CC</sub>	V
		V <sub>CC</sub> @ 3.0 V	-	150	-	
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs	V <sub>CC</sub> @ 4.5 V	-	40	-	ns/V
		V <sub>CC</sub> @ 5.5 V	-	25	-	
	Input Rise and Fall Time (Note 2)	V <sub>CC</sub> @ 4.5 V	-	10	-	201
t <sub>r</sub> , t <sub>f</sub>	ACT Devices except Schmitt Inputs	V <sub>CC</sub> @ 5.5 V	-	8.0	-	ns/V
TJ	Junction Temperature (PDIP)		_	_	140	°C
T <sub>A</sub>	Operating Ambient Temperature Range	-40	25	85	°C	
I <sub>ОН</sub>	Output Current – High	-	-	-24	mA	
I <sub>OL</sub>	Output Current – Low	-	-	24	mA	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1.  $V_{in}$  from 30% to 70%  $V_{CC}$ ; see individual Data Sheets for devices that differ from the typical input rise and fall times. 2.  $V_{in}$  from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

#### **DC CHARACTERISTICS**

	Parameter		74	AC	74AC			
Symbol		V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = –40°C to +85°C	Unit	Conditions	
			Тур	Guar	anteed Limits			
V <sub>IH</sub>	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	v	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$	
V <sub>IL</sub>	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$	
V <sub>OH</sub>	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	I <sub>OUT</sub> = –50 μA	
		3.0 4.5 5.5		2.56 3.86 4.86	2.46 3.76 4.76	v	$V_{IN} = V_{IL} \text{ or } V_{IH}$ -12 mA $I_{OH}$ -24 mA -24 mA	
V <sub>OL</sub>	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V	Ι <sub>ΟUT</sub> = 50 μΑ	
		3.0 4.5 5.5	- - -	0.36 0.36 0.36	0.44 0.44 0.44	v	$V_{IN} = V_{IL} \text{ or } V_{IH}$ 12 mA $I_{OL}$ 24 mA 24 mA	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	$V_{I} = V_{CC}, GND$	
I <sub>OLD</sub>	†Minimum Dynamic	5.5	-	-	75	mA	V <sub>OLD</sub> = 1.65 V Max	
I <sub>OHD</sub>	Output Current	5.5	-	-	-75	mA	V <sub>OHD</sub> = 3.85 V Min	
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	_	4.0	40	μΑ	$V_{IN} = V_{CC}$ or GND	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: I<sub>IN</sub> and I<sub>CC</sub> @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V<sub>CC</sub>.

#### **AC CHARACTERISTICS**

			74AC			74AC			
Symbol Parameter		V <sub>CC</sub> * (V)	T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF			T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF		Unit	Fig. No.
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	3.3 5.0	1.5 1.5	7.0 5.5	9.0 7.5	1.5 1.0	10.0 8.5	ns	3–5
t <sub>PHL</sub>	Propagation Delay	3.3 5.0	1.5 1.5	7.0 5.0	8.5 7.0	1.0 1.0	9.0 7.5	ns	3–5

\*Voltage Range 3.3 V is 3.3 V  $\pm$ 0.3 V.

Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

#### **DC CHARACTERISTICS**

			74A	СТ	74ACT			
Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = –40°C to +85°C	Unit	Conditions	
			Тур	Guar	anteed Limits			
V <sub>IH</sub>	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$	
V <sub>IL</sub>	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$	
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I <sub>OUT</sub> = -50 μA	
		4.5 5.5		3.86 4.86	3.76 4.76	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ -24 mA $V_{OH}$ -24 mA	
V <sub>OL</sub>	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I <sub>OUT</sub> = 50 μA	
		4.5 5.5		0.36 0.36	0.44 0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $V_{OL} = 24 \text{ mA}$ 24  mA	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	$V_{I} = V_{CC}, GND$	
$\Delta I_{CCT}$	Additional Max. I <sub>CC</sub> /Input	5.5	0.6	-	1.5	mA	$V_{I} = V_{CC} - 2.1 V$	
I <sub>OLD</sub>	†Minimum Dynamic	5.5	_	-	75	mA	V <sub>OLD</sub> = 1.65 V Max	
I <sub>OHD</sub>	Output Current		-	-	-75	mA	V <sub>OHD</sub> = 3.85 V Min	
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	_	4.0	40	μΑ	$V_{IN} = V_{CC}$ or GND	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

### **AC CHARACTERISTICS**

	Parameter	V <sub>cc</sub> * (V)	74ACT T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF			$74ACT$ $T_A = -40^{\circ}C$ to +85^{\circ}C $C_L = 50 \text{ pF}$			Fig. No.
Symbol								Unit	
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	5.0	1.0	-	9.0	1.0	10.0	ns	3–6
t <sub>PHL</sub>	Propagation Delay	5.0	1.0	-	9.0	1.0	10.0	ns	3–6

\*Voltage Range 5.0 V is 5.0 V  $\pm$ 0.5 V.

#### CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	$V_{CC} = 5.0 V$
C <sub>PD</sub>	Power Dissipation Capacitance	20	pF	V <sub>CC</sub> = 5.0 V

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC74AC32DG	SOIC-14	55 Units / Rail
MC74AC32DR2G	(Pb–Free)	2500 Units / Reel
MC74AC32DTR2G	TSSOP-14 (Pb-Free)	2500 Units / Reel
MC74ACT32DG	SOIC-14	55 Units / Rail
MC74ACT32DR2G	(Pb–Free)	2500 Units / Reel
MC74ACT32DTR2G	TSSOP–14 (Pb–Free)	2500 Units / Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

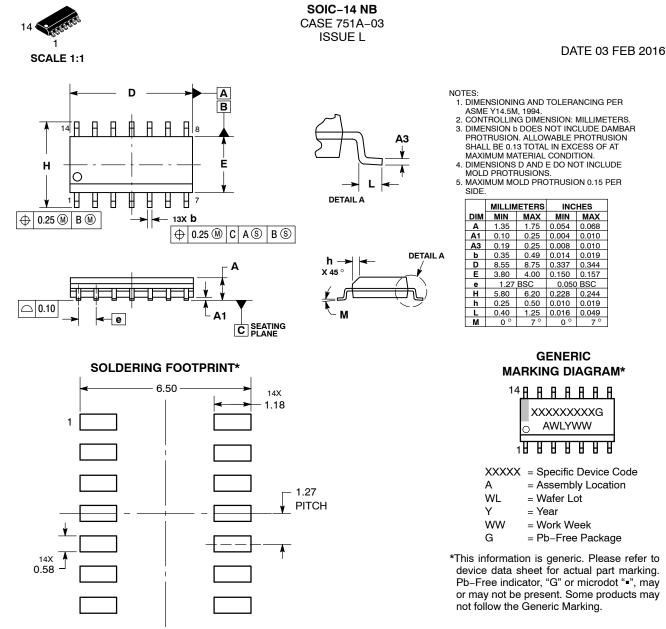
# DUSEM

0.068

0.019

0.344

0.244



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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#### DATE 03 FEB 2016

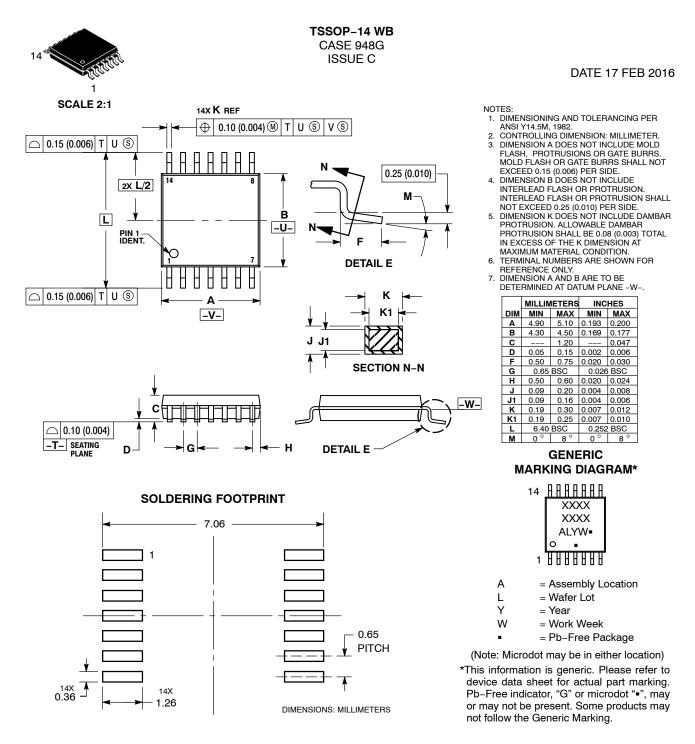
STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5:	STYLE 6:	STYLE 7:	STYLE 8:
PIN 1. COMMON CATHODE	PIN 1. CATHODE	PIN 1. ANODE/CATHODE	PIN 1. COMMON CATHODE
2. ANODE/CATHODE	2. CATHODE	2. COMMON ANODE	2. ANODE/CATHODE
3. ANODE/CATHODE	3. CATHODE	3. COMMON CATHODE	3. ANODE/CATHODE
4. ANODE/CATHODE	4. CATHODE	4. ANODE/CATHODE	4. NO CONNECTION
5. ANODE/CATHODE	5. CATHODE	5. ANODE/CATHODE	5. ANODE/CATHODE
6. NO CONNECTION	6. CATHODE	6. ANODE/CATHODE	6. ANODE/CATHODE
7. COMMON ANODE	7. CATHODE	7. ANODE/CATHODE	7. COMMON ANODE
8. COMMON CATHODE	8. ANODE	8. ANODE/CATHODE	8. COMMON ANODE
9. ANODE/CATHODE	9. ANODE	10. ANODE/CATHODE	9. ANODE/CATHODE
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